ABSTRACT

A method for annealing a structure formed by electrodeposition is provided, the method eomprising including providing the electrodeposition structure, the electrodeposition structure eomprising including an electroformed mold, the electroformed mold having a nominal thickness between and including 0.5mm to 8.0mm and having a melting temperature; heating the electrodeposition structure to a temperature between ambient temperature and the melting temperature of the electrodeposition structure; isostatically pressurizing the electrodeposition structure to a pressure above ambient pressure; cooling the electrodeposition structure to ambient temperature; and depressurizing the electrodeposition structure to ambient pressure.